## NSN 5961-01-212-5022

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-212-5022 **Inclosure Material:** Metal **Overall Length:** 0.700 inches **End Application:** 6130-01-109-6577; patroit missile **Mounting Facility Quantity: Mounting Method:** Threaded stud **Overall Width Across Flats:** 0.187 inches Thread Size: 0.112 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 200.0 reverse voltage, peak **Current Rating Per Characteristic:** 12.00 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Precious Material And Location:** Plated terminals gold **Precious Material:** Gold **Test Data Document:** 18876-11453852 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unc **Terminal Type And Quantity:** 1 solder stud and 1 threaded stud Shelf Life: N/a **Unit Of Measure:** 

Demilitarization:

Yes - demil/mli

Fiig:

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